MPS4250

Transistor

PNP Silicon

Features

• This is a Pb-Free Device*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector - Emitter Voltage	V _{CEO}	-40	Vdc	
Collector - Emitter Voltage	V _{CES}	-40	Vdc	
Collector - Base Voltage	V _{CBO}	′CBO –40		
Emitter - Base Voltage	V _{EBO}	-5.0	5.0 Vdc	
Collector Current - Continuous	Ic	-50	mAdc	
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	W mW/°C	
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C	

THERMAL CHARACTERISTICS

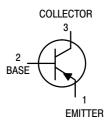
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

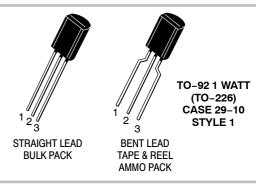
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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MARKING DIAGRAM



A = Assembly Location

Y = Year WW = Work Week ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MPS4250G	TO-92 (Pb-Free)	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MPS4250

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

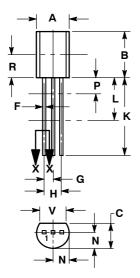
Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage (I _C = -5.0 mA)	V _{(BR)CES}	-40	_	Vdc
Collector – Emitter Sustaining Voltage (Note 1) $(I_C = -5.0)$	V _(BR) CEO(sus)	-40	-	Vdc
Collector – Base Breakdown Voltage $(I_C = -10 \mu A)$	V _{(BR)CBO}	-40	-	Vdc
Emitter – Base Breakdown Voltage ($I_E = -10 \mu A$)	V _{(BR)EBO}	-5.0	-	Vdc
Collector Cutoff Current $(V_{CB} = -50 \text{ V})$ $(V_{CB} = -40 \text{ V}, T_A = 65^{\circ}\text{C})$	I _{CBO}	- -	-10 -3.0	nA μA
Emitter Cutoff Current (V _{EB} = -3.0 V)	I _{EBO}	-	-20	nA
ON CHARACTERISTICS				
DC Current Gain $ \begin{array}{l} \text{(I}_C = -1.0 \text{ mA, V}_{CE} = -5.0 \text{ V)} \\ \text{(I}_C = -10 \text{ mA, V}_{CE} = -5.0 \text{ V)} \end{array} $	h _{FE}	250 250	_ _	-
Collector – Emitter Saturation Voltage (Note 1) $(I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA})$	V _{CE(sat)}	-	-0.25	Vdc
Base – Emitter Saturation Voltage (Note 1) $(I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA})$	V _{BE(sat)}	-	-0.9	Vdc
SMALL-SIGNAL CHARACTERISTICS			1	•
Output Capacitance $(V_{CB} = -5.0 \text{ V}, f = 1.0 \text{ MHz})$	C _{obo}	-	6.0	pF
Input Capacitance $(V_{EB} = -0.5 \text{ V}, f = 1.0 \text{ MHz})$	C _{ibo}	-	16	pF
Small–Signal Current Gain (I_C = -1.0 mA, V_{CE} = -5.0 V, f = 1.0 kHz) (I_C = -0.5 mA, V_{CE} = -5.0 V, f = 20 MHz)	h _{fe}	250 2.0	800 -	-
Noise Figure $ \begin{array}{l} \text{(I}_{C}=-20~\mu\text{A, V}_{CE}=-5.0~\text{V, R}_{S}=10~\text{k}\Omega,f=1.0~\text{kHz, P}_{BW}=150~\text{Hz)} \\ \text{(I}_{C}=-250~\mu\text{A, V}_{CE}=-5.0~\text{V, R}_{S}=1.0~\text{k}\Omega,f=1.0~\text{kHz, P}_{BW}=150~\text{Hz)} \end{array} $	NF	- -	2.0 2.0	dB

^{1.} Pulse Test: Pulse Width = 300 μs; Duty Cycle = 2.0%.

MPS4250

PACKAGE DIMENSIONS

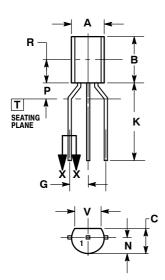
TO-92 (TO-226) 1 WATT CASE 29-10 **ISSUE O**



STRAIGHT LEAD **BULK PACK**



SECTION X-X



BENT LEAD TAPE & REEL AMMO PACK



NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1994.
 CONTROLLING DIMENSION: INCHES.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DI-MENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

	INC	CHES MILLIMET		IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
ſ	0.018	0.024	0.46	0.61
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.135		3.43	
٧	0.135		3.43	

STYLE 1: PIN 1. EMITTER

BASE COLLECTOR

NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: INCHES.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN
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В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
G	0.094	0.102	2.40	2.80
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.135		3.43	
٧	0.135		3.43	

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